

# **RV1S9160A**

HIGH CMR, 15Mbps CMOS OUTPUT, LOW FORWARD-CURRENT(IF) 3.3V/5V OPERATION, 5-PIN SOP PHOTOCOUPLER

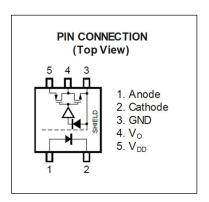
#### DESCRIPTION

The RV1S9160A is a photocoupler featuring high-speed switching up to 15Mbps with active low output logic which consist of an AIGaAs LED on the input side and an integrated circuit with a photodiode on the output.

This product enables to low current operation on 3.3V/5V power supply with high noise-tolerant CMR:50kV/us min. and high temperature operation up to T<sub>A</sub> = 125°C in logic interface circuit.

#### FEATURES

- High speed communication (15 Mbps)
- High temperature operation (-40 to +125°C)
- High common mode (dv/dt) tolerant (CM<sub>H</sub>, CM<sub>L</sub> = ±50 kV/µs MIN.)
- High isolation voltage (BV = 3750 Vr.m.s.)
- Low input drive current (IFHL = 2.0 mA MAX.)
- Low voltage power supply operation (V<sub>DD</sub> = 2.7 V ~ 5.5 V)
- Low pulse width distortion (PWD = 20 ns MAX.)
- Ordering number of tape product : RV1S9160ACCSP-100x#KC0 : 2500 pcs/reel
- Pb free product
- Safety standards approval
  - UL : UL1577, Double protection
  - CSA : CAN/CSA-C22.2 No.62368-1, Basic insulation
  - VDE : DIN EN 60747-5-5 (Option)



#### TRUTH TABLE

LED	OUTPUT
ON	L
OFF	Н

#### APPLICATIONS

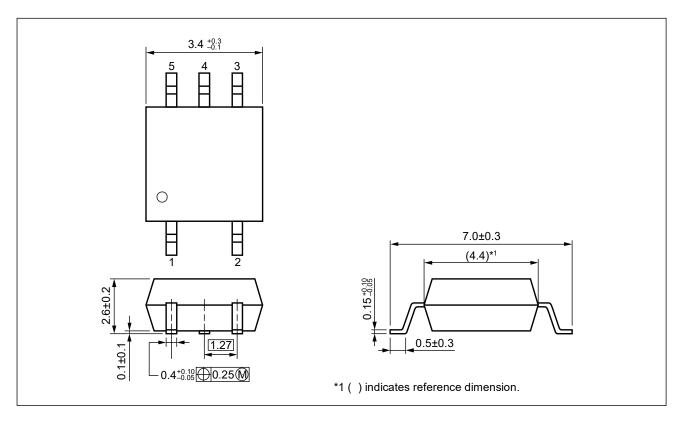
- Industrial inverter
- AC Servo
- FA Network
- Measurement, Control Equipment



# Data Sheet

R08DS0167EJ0101 Rev.1.01 Mar 06, 2020

# PACKAGE DIMENSIONS (UNIT : mm)



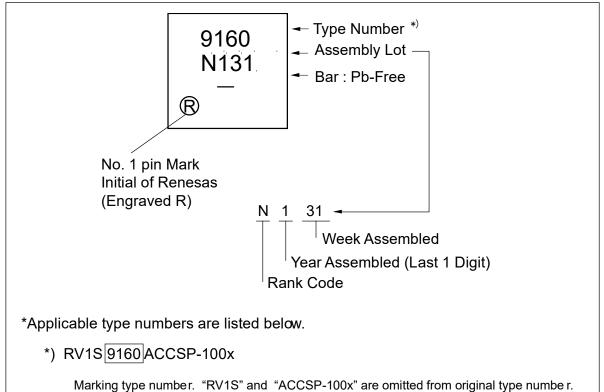
Weight: 0.08g (typ.)

# PHOTOCOUPLER CONSTRUCTION

Parameter	MIN.
Air Distance	4.2 mm
Creepage Distance	4.2 mm
Isolation Distance	0.2 mm







#### ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number <sup>*1</sup>
RV1S9160ACCSP- 100C	RV1S9160ACCSP -100C#SC0	Pb-Free (Ni/Pd/Au)	20 pcs (Tape 20 pcs cut)	Standard products (UL, CSA approved)	RV1S9160A
	RV1S9160ACCSP -100C#KC0		Embossed Tape 2 500 pcs/reel		
RV1S9160ACCSP- 100V	RV1S9160ACCSP -100V#SC0		20 pcs (Tape 20 pcs cut)	UL, CSA, DIN EN 60747-5-5	
	RV1S9160ACCSP -100V#KC0		Embossed Tape 2 500 pcs/reel	approved	

Notes: \*1. For the application of the Safety Standard, following part number should be used.

#### ABSOLUTELY MAXIMUM RATINGS (T<sub>A</sub> = 25°C, unless otherwise specified)

	Parameter	Symbol	Ratings	Unit
Diode	Forward Current *1	l <sub>F</sub>	20	mA
	Reverse Voltage	VR	5	V
Detector	Supply Voltage	V <sub>DD</sub>	6	V
	Output Voltage	Vo	6	V
	Output Current	lo	10	mA
	Power Dissipation *2	Pc	200	mW
Isolation V	/oltage <sup>*3</sup>	BV	3 750	Vr.m.s.
Operating	Ambient Temperature	T <sub>A</sub>	-40 to +125	°C
Storage T	emperature	T <sub>stg</sub>	-55 to +150	°C

Notes: 1. Reduced to 0.93 mA/°C at  $T_A = 110$ °C or more

2. Reduced to 4.57 mW/°C at  $T_A = 90^{\circ}C$  or more

3. AC Voltage for 1minite at  $T_A = 25^{\circ}$ C, RH = 60% between input and output. Pins 1-2 shorted together, 3-5 shorted together.



#### RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Low Level forward voltage	V <sub>FL</sub>	0		0.8	V
High Level Forward Current	Іғн	3		6	mA
Supply Voltage	V <sub>DD</sub>	2.7		5.5	V

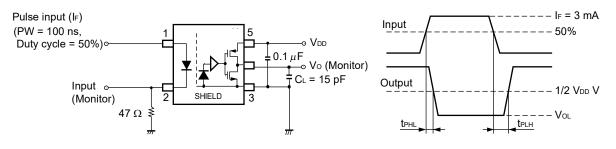
### ELECTRICAL CHARACTERISTICS

# (T<sub>A</sub> = - 40 to +125°C, $V_{DD}$ = 2.7 to 5.5 V, unless otherwise specified)

	Parameter	Symbol	Conditions	MIN.	TYP.* <sup>1</sup>	MAX.	Unit
Diode	Forward Voltage	VF	I <sub>F</sub> = 6 mA, T <sub>A</sub> = 25°C	1.4	1.55	1.7	V
	Reverse Current	IR	V <sub>R</sub> = 3 V, T <sub>A</sub> = 25°C			10	μA
	Terminal Capacitance	Ct	V <sub>F</sub> = 0 V, f = 1 MHz, T <sub>A</sub> = 25°C		30		pF
Detector	High Level Output Current	Iddh	I <sub>F</sub> = 0 mA		1.1	2	mA
	Low Level Output Current	IDDL	I <sub>F</sub> = 3 mA		1.0	2	
	High Level Output Voltage	Vон	I <sub>O</sub> = −3.2 mA, I <sub>F</sub> = 0 mA	V <sub>DD</sub> -1.0	V <sub>DD</sub>		V
			$I_0 = -20 \ \mu A, I_F = 0 \ mA$	V <sub>DD</sub> -0.1	V <sub>DD</sub>		
	Low Level Output Voltage	Vol	lo = 3.2 mA, l <sub>F</sub> = 3 mA		0.13	0.4	
			I <sub>0</sub> = 20 μA, I <sub>F</sub> = 3 mA		0.001	0.1	
Coupled	Threshold Input Voltage (H to L)	IFHL	V <sub>0</sub> < 0.4 V		1.0	2.0	mA
	Isolation Resistance	RI-0	$V_{I-O} = 1 \text{ kV}_{DC}, \text{RH} = 40 \text{ to } 60\%,$ $T_A = 25^{\circ}\text{C}$	10 <sup>11</sup>			Ω
	Isolation Capacitance	CI-O	V = 0 V, f = 1 MHz, T <sub>A</sub> = 25°C		0.5		pF
	Propagation Delay Time (H to L) <sup>*2</sup>	t <sub>PHL</sub>	I <sub>F</sub> = 3 mA ⇔ 0 mA V <sub>DD</sub> = 3.3 V,5 V		40	60	ns
	Propagation Delay Time (L to H)* <sup>2</sup>	t <sub>PLH</sub>	C∟ = 15 pF		38	60	
	Pulse Width Distortion*2	PWD	1		2	20	
	Propagation Delay Skew	t <sub>PSK</sub>	1			25	
	Rise Time	tr	]		5		
	Fall Time	t <sub>f</sub>			5		
	Common Mode	CM⊦	$I_F = 0 \text{ mA}, V_O > 4 V(V_{DD} = 5 V),$	50	60		kV/ <i>μ</i> s
	Transient Immunity at		$V_{O} > 2.3 V(V_{DD} = 3.3 V),$				
	High Level Output*3		V <sub>CM</sub> = 1.5 kV, T <sub>A</sub> = 25°C				
	Common Mode	CM <sub>L</sub>	I <sub>F</sub> = 3 mA,	50	60		
	Transient Immunity at		$V_{O} < 0.4 V(V_{DD} = 3.3 V, 5 V),$				
	Low Level Output* <sup>3</sup>		V <sub>CM</sub> = 1.5 kV, T <sub>A</sub> = 25°C				

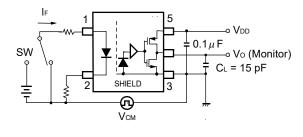


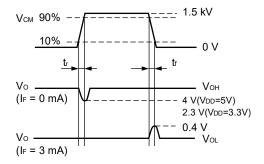
- Note2: 1. Typical values at T<sub>A</sub> = 25°C
  - 2. Test circuit for propagation delay time measurement



**Remark** C<sub>L</sub> includes probe and stray wiring capacitance.

3. Test circuit for common mode transient immunity measurement





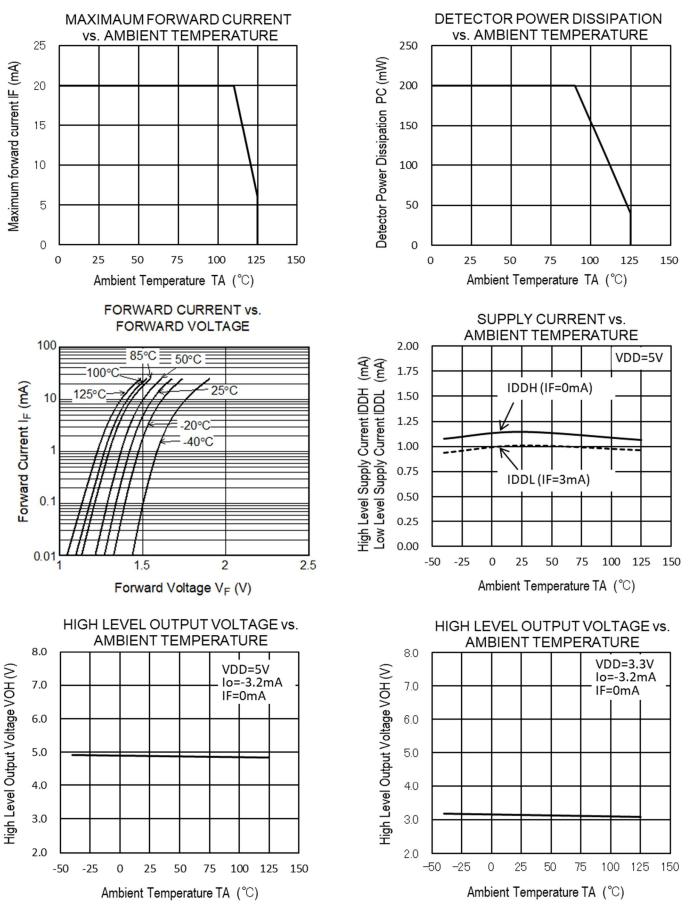
**Remark** C<sub>L</sub> includes probe and stray wiring capacitance.

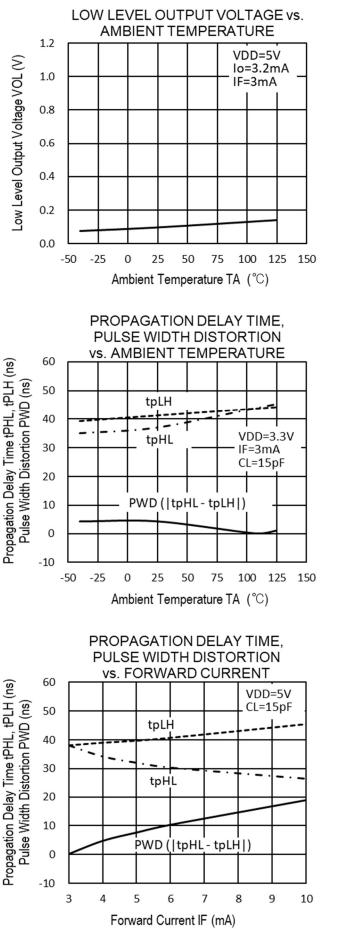
## USAGE CAUTIONS

- 1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
- 2. By-pass capacitor of more than 0.1  $\mu$ F is used between V<sub>DD</sub> and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.
- 3. Avoid storage at a high temperature and high humidity.

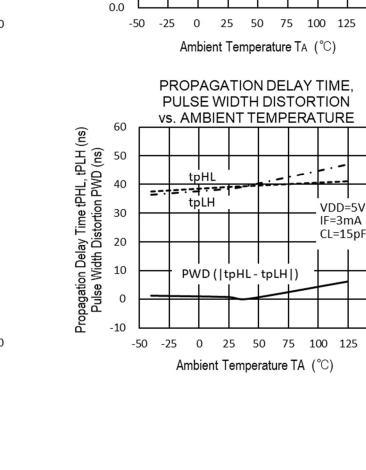


#### TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C, unless otherwise specified)





Remark The graphs indicate nominal characteristics.



2.5

2.0

1.5

1.0

0.5

Threshold Input Current IFHL (mA)

THRESHOLD INPUT CURRENT vs.

AMBIENT TEMPERATURE

VDD=5V

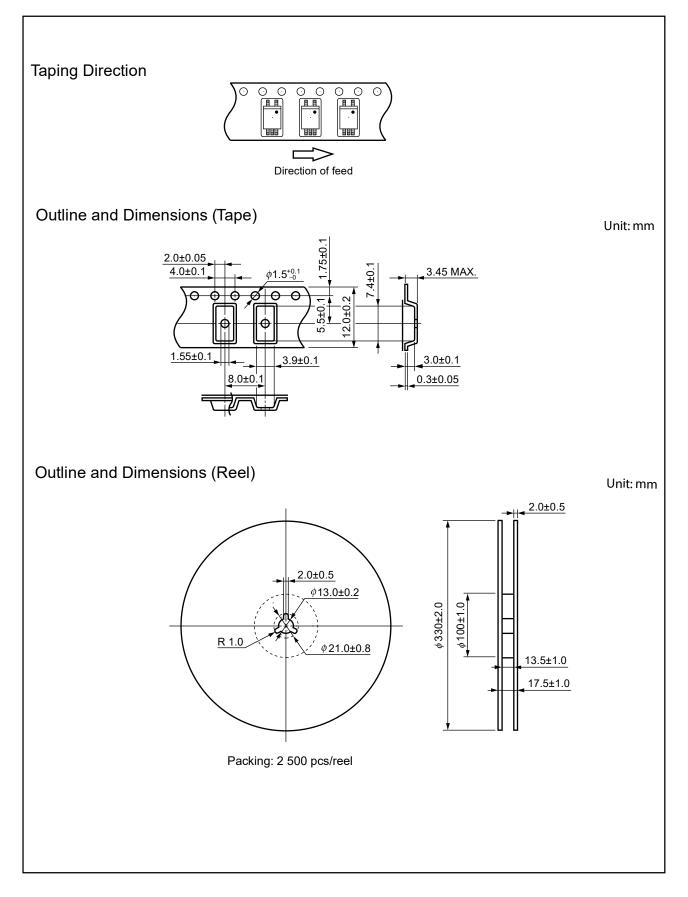
125

150

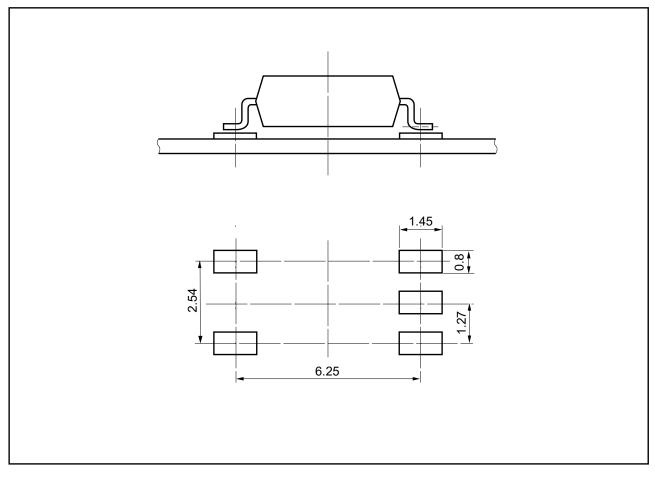
125 150



# TAPING SPECIFICATIONS (UNIT : mm)



# RECOMMENDED MOUNT PAD DIMENSIONS (UNIT : mm)



Remark All dimensions in this figure must be evaluated before use.



# NOTES ON HANDLING

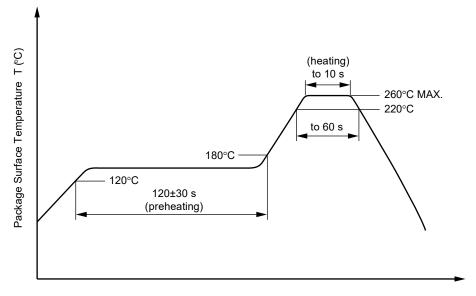
#### 1. Recommended soldering conditions

- (1) Infrared reflow soldering
  - Peak reflow temperature
  - Time of peak reflow temperature
  - Time of temperature higher than 220°C
  - Time to preheat temperature from 120 to 180°C
  - Number of reflows
  - Flux

#### 260°C or below (package surface temperature) 10 seconds or less 60 seconds or less 120±30 s Three Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of

0.2 Wt% is recommended.)

#### Recommended Temperature Profile of Infrared Reflow



Time (s)

#### (2) Wave soldering

- Temperature 260°C or below (molten solder temperature)
- Time 10 seconds or less
- Preheating conditions 120°C or below (package surface temperature)
- Number of times One (Allowed to be dipped in solder including plastic mold portion.)
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

#### (3) Soldering by Soldering Iron

Time (each pins)

- Peak Temperature (lead part temperature) 350°C or below
  - 3 seconds or less
- Flux
   Rosin flux containing small amount of chlorine
  - (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)
- (a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead
- (b) Please be sure that the temperature of the package would not be heated over  $100^{\circ}C$

#### (4) Cautions

- Flux Cleaning
  - Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.
- Do not use adhesives or coating materials including halogens to fix this device.
- 2. Cautions regarding noise

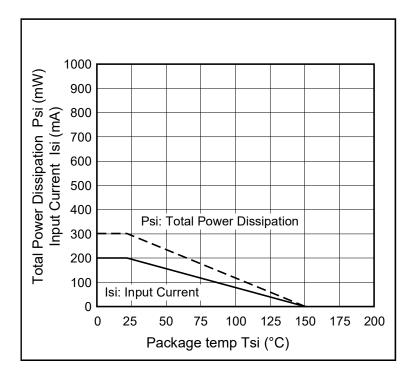
Be aware that when voltage is applied suddenly between the photocoupler's input and output or between  $V_{DD}$ -GND at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.



## SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

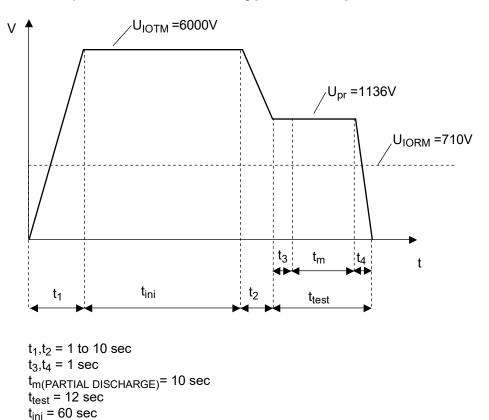
Parameter	Symbol	Rating	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		40/125/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) $U_{pr} = 1.6 \times U_{IORM}$ , $P_d < 5 \text{ pC}$	Uiorm Upr	710 1 136	V <sub>peak</sub> V <sub>peak</sub>
Test voltage (partial discharge test, procedure b for all devices) $U_{pr}$ = 1.875 × U <sub>IORM</sub> , Pd < 5 pC	Upr	1 331	V <sub>peak</sub>
Highest permissible overvoltage	Uютм	6 000	Vpeak
Degree of pollution (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303-11))	CTI	400	
Material group (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))		П	
Storage temperature range	Tstg	– 55 to +150	°C
Operating temperature range	TA	-40 to +125	°C
Isolation resistance, minimum value $V_{IO} = 500 \text{ V dc at } T_A = 25^{\circ}\text{C}$ $V_{IO} = 500 \text{ V dc at } T_A MAX. at least 100^{\circ}\text{C}$	Ris MIN. Ris MIN.	10 <sup>12</sup> 10 <sup>11</sup>	Ω Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current I <sub>F</sub> , Psi = 0) Power (output or total power dissipation) Isolation resistance	Tsi Isi Psi	150 200 300	°C mA mW
$V_{IO} = 500 \text{ V dc at } T_A = Tsi$	Ris MIN.	10 <sup>9</sup>	Ω

# Dependence of maximum safety ratings with package temperature

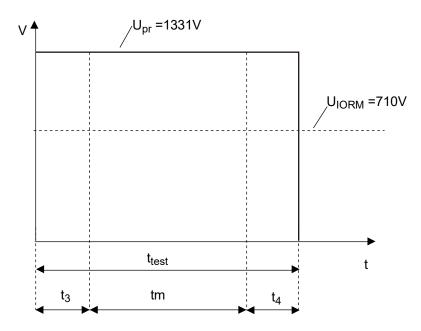












 $t_{3}, t_{4} = 0.1 \text{ sec}$  $t_{m}(\text{PARTIAL DISCHARGE}) = 1.0 \text{ sec}$  $t_{test} = 1.2 \text{ sec}$ 

Caution GaAs Products	This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.
	• Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
	<ol> <li>Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.</li> </ol>
	<ol><li>Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.</li></ol>
	Do not burn, destroy, cut, crush, or chemically dissolve the product.
	• Do not lick the product or in any way allow it to enter the mouth.

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